

Preparation and Characterization of a Layered Molybdenum Trioxide with Poly(o-anisidine) Hybrid Thin Film and Its Aldehydic Gases Sensing Properties

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Layered organic/inorganic hybrid thin film, which consist of MoO₃ with poly(*o*-anisidine) (PoANIS), were investigated by X-ray diffraction (XRD) analysis, field-emission scanning electron microscopy (FE-SEM) analysis, and gassensing properties analysis. The MoO₃ with PoANIS ((PoANIS)_xMoO₃) hybrid was prepared by an intercalation process, in which sodium ions were exchanged for PoANIS in MoO₃ thin films. The laminated structure of the (PoANIS)_x-MoO₃ hybrid was shown to have high periodic regularity by XRD analysis. The highly oriented (PoANIS)_xMoO₃ hybrid grains were observed on the substrate surface by XRD and FE-SEM analyses. The (PoANIS)_xMoO₃ hybrid had a large gas-sensing response to aldehydic gases, and little or no response to other volatile organic compounds. Moreover, the gas-sensing abilities of (PoANIS)_xMoO₃ were stronger for acetaldehyde than for formaldehyde, whereas other typical organic/MoO₃ hybrids showed an opposite response, which can be explained by solubility parameter theory.

Layered organic–inorganic hybrids have attracted much attention as novel functional materials because of their unique structure with various combinations of layered inorganic hosts and organic guests. ^{1,2} Layered inorganic hosts including exchangeable ions, such as clay, layered double hydroxide, and layered metal oxide semiconductor, can easily accommodate other ionic guests by ion exchange. ^{3–8} A notable feature of layered inorganic hosts is that their interlayer distance can expand to the size of intercalated organic molecules. Such hybrids have great potential for the development of materials with efficient properties, such as photofunctional materials, ^{9,10} electronic materials, ¹¹ and mechanically modified materials, owing to hybridization. ¹²

Layered orthorhombic molybdenum trioxide, MoO₃, possesses an n-type semiconducting properties. The layered structure of MoO₃ consists of double octahedra sheets that are composed of edge-sharing octahedral MoO₆ units, which have six oxygen ions and one molybdenum ion on their vertex and center, respectively. Reduced MoO₃, that is, Li_xMoO₃ or Na_xMoO₃, which is constructed with partially reduced MoO₃ with ion-exchangeable cations in the MoO₃ interlayers, is able to accommodate various organic cations. It has been reported that not only a lot of organic molecules but also several organic polymers can be intercalated into MoO₃ interlayers by several methods. $^{\rm 13-19}$

In our previous studies, we have reported that a series of organic/MoO₃ hybrids exhibits volatile organic compound (VOCs)-gas-sensing properties. 20,21 The detection of VOCs is judged on the basis of characteristic increases or decreases in their resistive responses. These resistive responses are dominated by a change in the density of carrier electrons in the MoO₃ layers, which is caused by VOC molecules adsorbing into the MoO₃ layer frameworks or interlayer organic

guests in the MoO₃ interlayers.^{20,21} Other VOCs-sensing materials and systems such as metal nanoparticles, 22 porous materials, ^{23–25} self-assembled surfactant thin films, ²⁶ conductive organic polymers,^{27–30} carbon black with organic polymers,³¹ and miniaturized gas chromatographic systems, 32 have already been reported. However, the significant and superior features of organic/MoO₃ hybrid sensors can be explained several ways. First, these sensors are capable of modifying internal organic guests to control their VOC-sensing responsiveness and selectivity. We have previously reported that organic/MoO₃ hybrids with polypyrrole and butylammonium show different response properties.²⁰ Second, the intercalation of several cationic organic components in MoO3 interlayers is a simple process. In the case of thin films, the reduced MoO₃, namely, Na₂MoO₃, thin film is soaked in a solution of organic cationic components to ion-exchange sodium ions for organic cations.^{33,34} Finally, the organic/ MoO₃ hybrid sensors show a distinct response to aldehydic gases, whereas they have almost no response to the other VOCs, such as toluene, xylene, and methanol.^{20,21} On the basis of above advantages, it is hoped that the organic/ MoO₃ hybrids can be used for developing new VOC-sensing devices.

In the present study, we investigated the preparation and characterization of a poly(o-anisidine)-intercalated MoO_3 hybrid powder $((PoANIS)_xMoO_3)$ and its thin film, and the gas-sensing abilities of the thin film were determined. In regards to the sensing abilities, several volatile organic compounds (VOCs) were investigated, and the $(PoANIS)_xMoO_3$ hybrid thin film was found to exhibit an increase in resistive response of 4.4% to 10 ppm acetaldehyde, while it showed a 2.4% increase in the resistive response to formaldehyde and hardly any response to other VOCs.

Experimental

Preparation of Na⁺-Intercalated MoO₃ Powders by Reduction Process. Nitrogen gas was bubbled through 500-mL distilled water for 45 min for deaeration. Sodium hydrosulfite (4.0 g, 23 mmol; Wako Chem.) and sodium molybdate dihydrate (120 g, 0.50 mol; Kanto Chem.) powders were added into the distilled water, and the solution was stirred in bubbling nitrogen until the powders dissolved. The MoO₃ powder (10 g, 69 mmol; Kanto Chem.) was added to the solution over 3 min to reduce the MoO₃ layers and to insert Na⁺ ions into the interlayers.³⁵ The Na⁺-intercalated MoO₃, [Na(H₂O)₂]_xMoO₃, was washed with distilled water and then dried at 90 °C for 1 day to obtain 4.5 g of fine blue powder.

Preparation of (PoANIS)_xMoO₃ Hybrid Powders by Ion-Exchange Process. An aqueous suspension (25 mL) of o-anisidine (3.0 g, 25 mmol) was mixed with aqueous HCl (2.3 mL, 12 mol dm⁻³); the resulting o-anisidine hydrochloride solution was added to sodium peroxodisulfate (75 mg, 0.33 mmol), which is a polymerization initiator. Then, the solution was stirred magnetically while bubbling with nitrogen for 30 min. The color of the solutions became reddish brown due to the polymerization of o-anisidine. After being stirred, the poly(o-anisidine) suspension was filtrated. [Na(H₂O)₂]_xMoO₃ powder (0.10 g) was added into the filtrate and stirred for 10 min to ion-exchange soluble poly(o-anisidine) with sodium ions. The resulting hybrid powder was collected by filtration, washed with ethanol and water, and then dried at 90 °C for 1 day to obtain 99 mg of fine blue powder.

Preparation of Buffer Layer on SiO₂/Si Substrate. LaAlO₃ (LAO) buffer layer was prepared on a silicon wafer with a thermally oxidized SiO₂ insulating layer, abbreviated as SiO₂/ Si, to adhere the MoO₃ films to the surface of the wafer effectively. The LAO-coated silicon substrate was prepared by using a solution method. The SiO₂/Si was cut into $2 \times 2 \text{ cm}^2$ sections. An excess amount of LAO precursor coat solution, which was a mixture of a stoichiometric amount of 0.1 mol dm⁻³ LaO_{1.5} precursor in xylene solution (Kojundo Chem.) and 3% Al₂O₃ precursor in acetic ester solution (Kojundo Chem.), was deposited on the SiO₂/Si substrate. The substrate was spin-coated at 500 rpm for 10 s to spread the solution for full substrate coverage; it was then quickly accelerated to 3000 rpm and allowed to continue spinning for 30 s. After being dried at 90 °C for 30 min, the substrate was annealed at 1000 °C for 30 min in air. The resulting substrate is referred to as LAO/SiO₂/Si.

Preparation of MoO₃ Thin Film by Chemical Vapor Deposition (CVD). The LAO/SiO₂/Si substrates were cut into 1×1 cm² sections. Before the deposition of MoO₃, a gold comb-type electrode, which had a 5×5 mm² areas with a $20\,\mu m$ gap and a $20\,\mu m$ linewidth, was formed on the buffer layers to measure the electrical resistance of MoO₃-based hybrid thin films. The MoO₃ thin films were prepared by the pyrolysis of molybdenum hexacarbonyl (Aldrich) in oxygen atmosphere by CVD. 36,37 The deposition experiments were performed under the following conditions: the total pressure was $110\,Pa$ with an oxygen flow rate of $50\,m$ L min⁻¹, the source temperature was $40\,^{\circ}$ C, the substrate temperature was $500\,^{\circ}$ C, and the deposition time was $15\,m$ in.

Insertion of Sodium Ions into Interlayers of MoO₃ Thin Films by Reduction Process. Nitrogen gas was bubbled through 15 mL of distilled water for 25 min for deaeration. Sodium hydrosulfite (2.3 mmol; Wako Chem.) and sodium molybdate dihydrate (25 mmol; Kanto Chem.) powders were added into the distilled water, and the solution was stirred in bubbling nitrogen until the

Chart 1. (a) Aniline; (b) o-anisidine.

powders were dissolved. The MoO_3 thin films were soaked in the solution for 25 s to reduce MoO_3 layers and to insert Na^+ ions in the interlayers. The Na^+ -intercalated MoO_3 films, [Na- $(H_2O)_2]_xMoO_3$, were washed with distilled water quickly and then dried at 90 °C for 30 min.

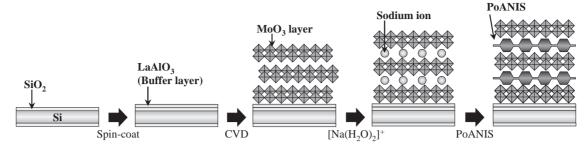
Intercalation of Poly(o-anisidine) or Polyaniline into Interlayers of MoO₃ Thin Films by Ion-Exchange Process. aqueous suspension (15 mL) of o-anisidine or aniline, as shown in Chart 1, (16.4 mmol) was mixed with aqueous HCl (1.5 mL, 12 mol dm $^{-3}$); the resulting o-anisidine or aniline hydrochloride solution was added to sodium peroxodisulfate (0.22 mmol) as a polymerization initiator. The solution was then stirred magnetically while bubbling with nitrogen for 30 min. The color of the solutions became reddish brown and dark blue due to the polymerization of o-anisidine and aniline, respectively. After being stirred, [Na(H₂O)₂]_rMoO₃ films were soaked in the suspension for 30 s to ion-exchange Na⁺ with soluble poly(o-anisidine) or polyaniline. The resulting hybrid films were washed with distilled water quickly and then dried at 90 °C for 30 min. Poly(o-anisidine) and polyaniline are referred to as PoANIS and PANI, and the corresponding MoO₃ hybrids are referred to as (PoANIS)_rMoO₃ and (PANI)_xMoO₃, respectively. Scheme 1 shows the intercalation procedure for (PoANIS)_xMoO₃ and (PANI)_xMoO₃ hybrid thin films.

X-ray Diffraction Analysis of Hybrids. X-ray diffraction analysis (XRD) of MoO₃, [Na(H₂O)₂]_xMoO₃, (PANI)_xMoO₃, and (PoANIS)_xMoO₃ hybrids was carried out with a Rigaku RINT-2100 XRD apparatus with Cu K α set at 1.54 Å, and operating at 40 kV and 30 mA. The XRD patterns were measured in the $2\theta/\theta$ mode within a 2θ range of 2–60° with a scan rate of 3 deg min⁻¹.

Thermogravimetry and Differential Thermal Analysis of the $(PoANIS)_xMoO_3$ Hybrid Powders. The thermogravimetry (TG) and differential thermal analyses (DTA) of the $(PoANIS)_xMoO_3$ hybrid powders was carried out with an Ulvac TGD7000RH-S TG/DTA instrument. About 12 mg of powder was placed into an alumina vessel and heated at a rate of 10 $^{\circ}$ C min $^{-1}$ up to 600 $^{\circ}$ C in air.

Field-Emission Scanning Electron Microscopy Analysis of Hybrids. Field-emission scanning electron microscopy analysis (FE-SEM) was carried out with a JEOL JSM-6355FM microscope. All of the substrates were attached with Ag paste to the sample holder, and then dried at 90 °C for 90 min under vacuum before analysis.

Electric Properties Analysis of Hybrids. The gas-sensing properties of the (PoANIS)_xMoO₃ hybrid were measured in a flow apparatus, as shown in Fig. 1. Aldehydic gases, which were 181.0 ppm formaldehyde in nitrogen and 192.0 ppm acetaldehyde in nitrogen, were made by Sumitomo Seika Chemicals Co., Ltd. Chloroform, alcohols, acetone, and aromatics gases were generated by a Gastec PD-1B gas-generation apparatus. These gases were used as standard VOC gases in the sensing properties measurement. A couple of gold wires were attached to the gold comb-type electrode using silver paste. The (PoANIS)_xMoO₃ thin film was placed in the homeothermic chamber heated at 100 °C, and the re-



Scheme 1. Schematic depiction of preparation for (PoANIS)_xMoO₃ and (PANI)_xMoO₃ hybrid thin films.

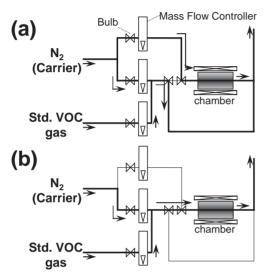


Fig. 1. Schematic diagram of a flow apparatus for the VOCs-sensing properties analysis. The (PoANIS)_xMoO₃ hybrid thin film was placed in the homeothermic chamber. Arrows indicate gas flow directions: (a) the pure nitrogen gas was flowed, and (b) 10 ppm VOCs with nitrogen carrier was flowed in the chamber.

sistance signal of the hybrid was measured directly through the gold wires. The VOC concentrations were precisely controlled by the flow system with a mass flow controller. The total flow was always 200 mL min⁻¹. After pure nitrogen gas was flowed, VOCs with a nitrogen carrier, which was a dilution of standard VOC gases with nitrogen carrier, were flowed for 10 min, and then the flow gas was again changed to pure nitrogen gas. The response was defined as Eq. 1,

$$S = \frac{R_g}{R_o} - 1,\tag{1}$$

where S, $R_{\rm g}$, and $R_{\rm a}$ denote the response, the resistances in VOCs and pure nitrogen gas just before VOCs flowed to the chamber, respectively.

Results and Discussion

Structural Study of (PoANIS)_x**MoO**₃ **Hybrid.** The (PoANIS)_xMoO₃ hybrid powder was synthesized in order to characterize it. The series of (0k0) XRD peaks for the (PoANIS)_xMoO₃ hybrid powder showed characteristic high periodic regularity in its alternating laminating structure, as can be seen in Fig. 2. The (010) diffraction peak of the [Na(H₂O)₂]_xMoO₃ powder shifted from the MoO₃ (020) peak to a lower angle, and the series of MoO₃ (0k0) peaks disap-

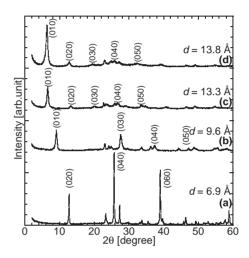


Fig. 2. XRD patterns of the (a) MoO_3 , (b) $[Na(H_2O)_2]_x$ - MoO_3 , (c) $(PANI)_xMoO_3$, and (d) $(PoANIS)_xMoO_3$ hybrid powders measured at ca. $20\,^{\circ}$ C. The d values mean the interlayer distances of powders from (0k0) peaks.

peared, indicating the expansion of interlayer spaces by 2.7 Å due to the intercalation of sodium ions. The (0k0) peaks of (PoANIS)_xMoO₃ hybrid powder shifted downward from that of [Na(H₂O)₂]_xMoO₃ powder with an increase in the volume of the guest ions, as shown in Fig. 2. The interlayer distance of the (PANI)_xMoO₃ hybrids was in agreement with the molecular size of the benzene ring, indicating a perpendicular orientation of PANI chains to the MoO3 sheets. In the case of the (PoANIS), MoO₃ hybrid, the interlayer distance was almost the same as that for the (PANI)_xMoO₃ hybrid, even though PoANIS has a methoxy group into ortho position. These results suggest that the benzene rings of PoANIS are tilted from the normal line against the MoO₃ layer. On the basis of structural calculations of aniline and o-anisidine trimers using MM2 calculations, the benzene rings of aniline queued up in parallel, while those of o-anisidine were alternately tilted.

Figure 3 shows the TG/DTA curve of $(PoANIS)_xMoO_3$ hybrid powder. Heat treatment up to $270\,^{\circ}\text{C}$ caused endothermic weight loss for the $(PoANIS)_xMoO_3$ hybrid, which was attributed to the release of adsorbing water and/or internal crystal water, and exothermic weight loss of 14.5% over $270\,^{\circ}\text{C}$, which may be due to the thermal decomposition of the intercalated PoANIS. From the weight loss in the TG curve, the x value of the $(PoANIS)_xMoO_3$ hybrid was calculated to be 0.21. The elemental analysis data of dried $(PoANIS)_xMoO_3$ hybrid powder (C, 10.55; H, 1.48; N, 1.74%) was used to determine the chemical formula $(C_7H_8ON)_{0.21}MoO_3 \cdot 0.39H_2O$, indicat-

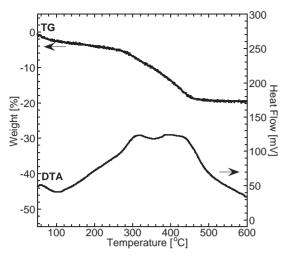


Fig. 3. TG and DTA patterns of the (PoANIS)_xMoO₃ hybrid in air.

ing water molecules intercalated into the MoO₃ interlayers during the reduction and ion-exchange processes.

Characterization of (PoANIS)_xMoO₃ Hybrid Thin Films. For the measurements of the electrical properties, the (PoANIS)_xMoO₃ hybrid should be processed into a thin film on a comb-type electrode. However, it is difficult to form the hybrid into as a thin film owing to the different chemical and physical properties of the organic guest and inorganic MoO₃ host. Therefore, the preparation of the (PoANIS)_xMoO₃ hybrid thin film was carried out in the following order: 1) deposition of MoO₃ thin films on silicon substrate with LaAlO₃ (LAO) buffer layer and gold comb-type electrode by a chemical vapor deposition method (CVD); 2) insertion of sodium ions into a MoO₃ interlayers by a reduction process; and 3) intercalation of organic components into MoO₃ interlayers by an ion-exchange process.

Figure 4 shows XRD patterns of the MoO₃ and MoO₃based hybrids thin films. The series of (0k0) XRD peaks for the MoO3 and MoO3-based hybrids thin films also showed the characteristic high periodic regularity. In addition, interlayer distances of thin films were almost same value as those of powders, indicating that fine layered MoO₃ thin film can be made on LAO/SiO₂/Si substrate by CVD. Trace (a) in Fig. 4 is the pattern of the MoO₃ thin film deposited on the surface of the LAO/SiO₂/Si substrate. The (010) diffraction peak of [Na(H₂O)₂]_xMoO₃ thin film is also shown (Fig. 4b). It showed that the thin film was prevented from peeling off during an intercalation of sodium ions due to a reduction process. Traces (c) and (d) are the patterns of the (PANI)_xMoO₃ and (PoANIS)_xMoO₃ hybrids, respectively. Moreover, all of the XRD patterns in Fig. 4 showed only (0k0) peaks, indicating that MoO₃, [Na(H₂O)₂]_xMoO₃, and (PoANIS)_xMoO₃ hybrid films have their b-axis oriented highly toward the normal line against the substrate which have the LAO buffer layer. These results of XRD profiles were reproducible with independent specimens. The lattice mismatch between the in-plane average length of the a- and c-axes of MoO₃ (orthorhombic) and the a-axis of LAO (cubic) was 1.0%. MoO₃, $[Na(H_2O)_2]_x$ -MoO₃ and organic/MoO₃ hybrid grains can form b-axis oriented highly not on large lattice mismatch substrates, such as

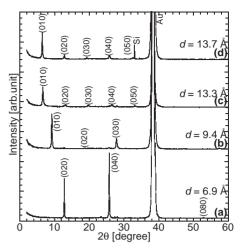


Fig. 4. X-ray diffraction patterns of the MoO₃ and MoO₃-based hybrids thin films on the LAO/SiO₂/Si substrate measured at ca. 20 °C: (a) MoO₃; (b) [Na(H₂O)₂]_xMoO₃; (c) (PANI)_xMoO₃ hybrid; and (d) (PoANIS)_xMoO₃ hybrid. The *d* values mean the interlayer distances of thin films from (0*k*0) peaks.

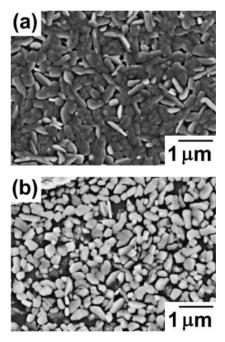
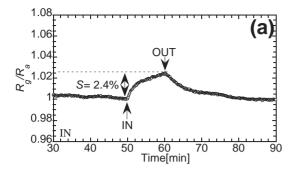


Fig. 5. The surface images of (a) MoO₃ and (b) (PoANIS)_x-MoO₃ hybrid thin films by FE-SEM.

MgO, but on LAO single crystal substrate.¹⁴ In addition, *b*-axis oriented MoO₃ hybrids including butylammonium ions on the LAO buffer layer has been reported.³⁸ The LAO buffer layer is explained to have been crystallized. Figure 5 shows the surface appearance of MoO₃ and (PoANIS)_xMoO₃ hybrids. The MoO₃ film consisted of oval-like thin grains, which were oriented toward the plane of the substrate surface and combined together (Fig. 5a). The hybrid grains should peel off of the substrate unless the MoO₃ grains are oriented toward the substrate, because the expanded layered MoO₃ grains interfere with each other during the intercalation of sodium ions and PoANIS into the MoO₃ interlayers. The (PoANIS)_xMoO₃ hy-



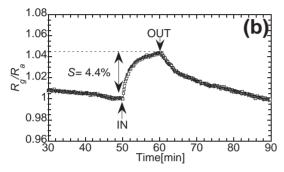


Fig. 6. Normalized resistive profiles of (PoANIS)_xMoO₃ hybrid. After the pure nitrogen gas was flowed, 10 ppm VOCs with nitrogen carrier were flowed for 10 min, and then the flow gas was again changed to the pure nitrogen gas. VOCs are (a) 10 ppm formaldehyde and (b) 10 ppm acetaldehyde.

brid film had grain sizes of approximately $300 \,\mathrm{nm}$ (Fig. 5b). The electric resistance of the $(\mathrm{PoANIS})_x\mathrm{MoO}_3$ hybrid film was measured on the mega ohm level to be approximately $6 \times 10^7 \,\Omega$ under a nitrogen atmosphere at $100 \,^{\circ}\mathrm{C}$, because $(\mathrm{PoANIS})_x\mathrm{MoO}_3$ hybrid grains were prevented from peeling off.

Electric Properties of (PoANIS), MoO3 Hybrid Thin Figure 6 shows the increasing resistive response of the (PoANIS)_xMoO₃ hybrid thin film to aldehydic gases. The increase in S was 2.4% in the presence of 10 ppm formaldehyde for 10 min. An increase in S of 4.4%, when the (PoANIS)_xMoO₃ hybrid thin film was exposed to 10 ppm of acetaldehyde for 10 min, was also observed. The magnitudes of the responses of the (PoANIS)_xMoO₃ hybrid and the (PANI)_rMoO₃ hybrid to formaldehyde, acetaldehyde, and several other VOCs are summarized in Table 1. The (PoANIS)_x-MoO₃ hybrid showed an increase in resistive response to aldehydic and alcohol gases; in particular, there was a distinct response to aldehydic gases. In contrast, the (PoANIS)_xMoO₃ hybrid showed no response to chloroform, acetone, aromatics. These results indicate that the sensing properties of the (PoANIS)_xMoO₃ hybrid are affected by functional groups of the VOCs. The (PoANIS)_xMoO₃ hybrid thin film exhibited the same level of performance as the (PANI)_xMoO₃ hybrid. The organic/MoO₃ hybrids have a great potential to detect aldehydic gases.

It should be noted that the sensing properties of the $(PoANIS)_xMoO_3$ hybrid in terms of response to aldehydic gases were different from those of the $(PANI)_xMoO_3$ hybrid,

Table 1. Magnitudes of the Response (*S*) of the (PoANIS)_x-MoO₃ and the (PANI)_xMoO₃ Hybrids to Several VOCs and Solubility Parameters of the VOCs

VOCs	S/%		Solubility parameter
	(PoANIS) _x MoO ₃ ^{a)}	(PANI) _x MoO ₃ ^{b)}	$/(MPa)^{1/2}$
Formaldehyde	2.4	8.0	_
Acetaldehyde	4.4	3.8	21.1
Chloroform	< 0.1	0.3	19.0
Methanol	0.5	0.2	29.7
Ethanol	0.3	0.3	26.0
Acetone	< 0.1	< 0.1	20.3
Benzene	< 0.1	_	18.8
Toluene	< 0.1	< 0.1	18.2
Xylene	< 0.1	< 0.1	18.0

a) 10 ppm VOCs. b) 50 ppm VOCs (Ref. 38).

as shown in Table 1. Typical organic/MoO3 hybrids, e.g., the (PANI)_xMoO₃ hybrid, showed the strongest response to formaldehyde, medium response to acetaldehyde, and little response to *n*-butylaldehyde and *n*-hexylaldehyde, indicating that molecular sizes of aldehydic molecules affect the sensing properties of the organic/MoO₃ hybrids. However, the (PoANIS), MoO₃ hybrid responded to acetaldehyde more strongly than to formaldehyde, as shown in Fig. 6. The normalized resistances of the (PANI)_xMoO₃ hybrid increased to 8.0 and 3.8% in response to 50 ppm formaldehyde and acetaldehyde, respectively, ³⁹ while those of the (PoANIS), MoO₃ hybrid increased to 2.4 and 4.4% in response to 10 ppm formaldehyde and acetaldehyde, respectively. The signals of two sensors that respond differently to two target chemicals should be calculated to determine the exact concentrations of them. It is expected that the (PoANIS)_xMoO₃ hybrid can be used with typical organic/MoO₃ hybrids for the detection and determination of the exact concentration of formaldehyde and acetaldehyde.

The resistive transitional response of organic/MoO₃ hybrids was caused by VOCs that penetrate into their interlayers.²⁰ Therefore, the interaction of VOCs and interlayer organic components affects the VOC sensing properties. These results can be explained by the solubility parameter. The solubility of a solvent in a polymer is improved when the solubility parameter values of the polymer and the solvent are close to each other. The values of the solubility parameter for solvents are based on their heat of vaporization.⁴⁰ The values for polymers are given as Eq. 2.

$$\delta = \frac{\rho}{M} \times \sum F_i,\tag{2}$$

where δ , ρ , M, and F_i denote the solubility parameter [(MPa)^{1/2}], density [g cm⁻³], molecular weight per unit, and group molar attraction constants, respectively.⁴¹ The solubility parameters of PANI and PoANIS were calculated to be 19.1 and 20.5 (MPa)^{1/2} using Small's and Hoy's F_i constants.^{40–42} The solubility parameter of acetaldehyde has been reported to be 21.1 (MPa)^{1/2},⁴⁰ indicating that acetaldehyde penetrates into PoANIS better than into PANI. Therefore, the large response to acetaldehyde was obtained with the (PoANIS)_x-MoO₃ hybrid.

Conclusion

In the present work, the sensing properties of $(PoANIS)_x$ -MoO₃ hybrid thin films were investigated. The $(PoANIS)_x$ -MoO₃ hybrid detected aldehydic gases, whereas it had no response toward other VOCs. The $(PoANIS)_x$ MoO₃, in addition, showed a stronger response to acetaldehyde than to formaldehyde because of the high solubility of acetaldehyde into the interlayer organic components of PoANIS. The responsiveness to aldehydic gases can be controlled by the organic components.

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